arXiv:1910.05507v1 [quant-ph] 12 Oct 2019

Preparing squeezed spin states in a spin-mechanical hybrid system with silicon-vacancy centers

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(Dated: January 24, 2022)

We present and analyze an effective scheme for preparing squeezed spin states in a novel spinmechanical hybrid device, which is realized by a single crystal diamond waveguide with built-in silicon-vacancy (SiV) centers. After studying the strain couplings between the SiV spins and the propagating phonon modes, we show that long-range spin-spin interactions can be achieved under large detuning condition. We model these nonlinear spin-spin couplings with an effective one-axis twisting Hamiltonian, and find that the system can be steered to the squeezed spin states in the practical situations. This work may have interesting applications in high-precision metrology and quantum information.

I. INTRODUCTION

Solid defects in diamond including nitrogen-vacancy (NV) [1], silicon-vacancy (SiV) [2–4], and germanium vacancy (GeV) [5] color centers have attracted great interest in recent years. With the advantage of long spincoherence times, they provide promising platforms for quantum sensing and quantum information processing. A most prominent example is the NV center, for which the detection of weak signals [6], design of quantum logic gates [7–9], and storage or transfer of quantum information [10–14] have been investigated theoretically and experimentally. However, SiV centers are increasingly recognized as more attractive in some cases because they provide favorable optical properties such as bright, spectrally stable emission and very large strain susceptibility. In particular, recent demonstrations of long spincoherence times (~ 10 ms at low temperature) [15], and spin-photon interfaces [16], as well as a variety of quantum controls [17–24], make the SiV center a good memory qubit. More importantly, the very recent research shows that the strong strain couplings between the individual SiV center spins and the propagating phonon modes can be achieved [25]. This may set a base for manipulating the quantum states of SiV centers via the spin-phonon couplings.

As spin-based quantum technology evolves, there has been a considerable effort to manipulate the solid defect centers with mechanical driving [26]. Generally speaking, the static strain will generate energy shifts in the ground states, and the resonant a.c. strain field can coherently drive electron spin transitions. Thus far, the strong mechanical driving spin transitions with NV centers or divacancy centers in silicon carbide have been experimentally demonstrated [27–29]. However, as the sublevels of the ground state in NV centers are defined within the same orbital, the strain susceptibility is very weak ($\sim 10^9$ Hz/strain) [29–31]. By contrast, for SiV centers, because the ground states are defined in distinct orbital branches, they provide much larger strain susceptibility ($\sim 10^{15}$ Hz/strain) [20–23], and are more attractive to structure spin-mechanical hybrid devices. To further explore the potential of the spin-mechanical hybrid quantum systems, it is very appealing to steer the collective spins to the entangled states or the spin squeezed states (SSSs).

Arising from quantum correlation of collective spin systems, spin squeezing means partly cancel out fluctuations in one direction at the expense of those enhanced in the other directions [32–34]. Providing the ability to interrogate a physical system and precisely measure its observables, SSSs are fundamental to quantum information and high-precision metrology [35–37]. After decades of development, several schemes for preparing the SSSs with large atomic ensembles have been demonstrated. For instance, one can directly transfer the SSSs from the optical field to the atomic ensembles [38–40]. However, in this protocol, the degree of spin squeezing is limited by the quality of the input optical field. Other promising schemes include quantum non-demolition measurement [41, 42], or cavity squeezing [43–46]. As for spinmechanical hybrid architectures, the spin-phonon couplings can be utilized for driving the collective spins. Specifically, an effective scheme for preparing the SSSs with NV centers through mechanical driving has been theoretically studied in Ref. [47]. However, because the coupling interactions between NV spins and mechani-

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cal phonon modes are very weak, further experimental demonstrations are needed to verify its feasibility.

In this work, we propose an experimentally feasible scheme for generating the SSSs with SiV centers in a novel spin-mechanical hybrid device. In particular, the setup under consideration is realized by a diamond waveguide with SiV spins embedded. We first describe the strain couplings between the SiV centers and the propagating phonons, and show that the long-range spin-spin interactions can be obtained under large detuning condition. We model these nonlinear spin-spin couplings with an effective one-axis twisting Hamiltonian. and find that the system can be steered to SSSs as time envolves. We further study the effects of decoherence processes with numerical simulations, showing that our scheme is feasible in the realistic conditions. The benefits of this spin-mechanical hybrid device are quite diverse. For one thing, SiV centers provide long spin-coherence times, and their ground states can be tuned by external magnetic fields via Zeeman effect. For another, the recent research shows that the spin-phonon couplings can reach $2\pi \times 14$ MHz even for single SiV centers [25], which far exceeds the decoherence rates. Because the collective spin-phonon couplings are used for spin squeezing in our scheme, the coupling strength would further be enhanced. Apart from SSSs, there are more potential applications utilizing this hybrid quantum device, such as the entanglement detections [48].

II. THE SETUP

A. Electronic structure of the SiV centers

As shown schematically in Fig. 1(a), the setup under consideration is realized by a single crystal diamond waveguide with built-in SiV centers. In particular, we consider a waveguide with size (l, w, t), and focus on the quasi-one-dimensional (1D) condition $l \gg \{w, t\}$. We suppose the symmetry axis of the SiV centers is along the z axis, and the compression phonon modes supported by the waveguide is along the x axis. In the diamond lattice,

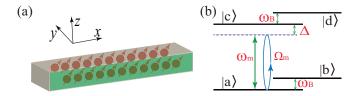


FIG. 1. Schematic design and operation of the setup. (a) The SiV center ensemble is embedded in a quasi-1D diamond waveguide. (b) In the presence of static magnetic field, the ground states of each SiV center can be mapped to a four-level system, and the spin transitions induced by the mechanical phonon modes are between $|a\rangle \leftrightarrow |c\rangle$ and $|b\rangle \leftrightarrow |d\rangle$. In the case without magnetic field, the SiV ground states simplify to a two level system, denoted as $|a\rangle$ and $|c\rangle$.

the SiV center is a point defect in which a silicon atom is positioned between two adjacent missing carbon atoms. The electronic ground state of SiV center consists of an unpaired hole with spin S = 1/2, which can occupy one of the two degenerate orbital states $|e_x\rangle$ or $|e_y\rangle$. In the presence of an external magnetic field $\vec{B} = B_z \vec{e}_z$, the SiV center spin is captured by Hamiltonian (let $\hbar = 1$)

$$\hat{H}_{SiV} = -\lambda_{so}\hat{L}_z\hat{S}_z + \hat{H}_{JT} + f\gamma_L B_z\hat{L}_z + \gamma_s\vec{B}\cdot\vec{S},\quad(1)$$

where $\lambda_{SO} > 0$ is the spin-orbit coupling constant, \hat{L}_z and \hat{S}_z are the projections of the dimensionless angular momentum and spin operators $\hat{\vec{L}}$ and $\hat{\vec{S}}$ onto the symmetry (z) axis of the center, \hat{H}_{JT} is the Jahn-Teller (JT) effect, $f \approx 0.1$ is the reduced orbital Zeeman effect, and $\gamma_L(\gamma_s)$ is the orbital (spin) gyromagnetic ratio.

In weak magnetic field environment, the SiV spin Hamiltonian (1) is dominated by the spin-orbit coupling, with a constant $\lambda_{SO} \simeq 2\pi \times 45$ GHz. This coupling interaction splits the ground state manifold into two lower states $\{|e_-,\downarrow\rangle, |e_+,\uparrow\rangle\}$ and two upper states $\{|e_+,\downarrow\rangle, |e_-,\uparrow\rangle\}$, where $|e_{\pm}\rangle = (|e_x\rangle \pm i|e_y\rangle)/\sqrt{2}$ are eigenstates of the angular momentum operator, $\hat{L}_z |e_{\pm}\rangle = \pm |e_{\pm}\rangle$. The reduced orbital Zeeman term can be neglected in our discussion, as it does not affect the results. In addition, the JT interaction \hat{H}_{JT} with strength $\Upsilon = \sqrt{\Upsilon_x^2 + \Upsilon_y^2} \ll \lambda_{SO}$ results in a mixing between the orbital angular momentum states $|e_+\rangle$ and $|e_-\rangle$. Putting everything together, diagonalization of the SiV spin Hamiltonian (1) leads to a four-level system [22–25], with eigenstates

$$\begin{aligned} |a\rangle &= (\cos\theta |e_x\rangle - i\sin\theta e^{-i\phi} |e_y\rangle) |\downarrow\rangle, \\ |b\rangle &= (\cos\theta |e_x\rangle + i\sin\theta e^{i\phi} |e_y\rangle) |\uparrow\rangle, \\ |c\rangle &= (\sin\theta |e_x\rangle + i\cos\theta e^{-i\phi} |e_y\rangle) |\downarrow\rangle, \\ |d\rangle &= (\sin\theta |e_x\rangle - i\cos\theta e^{i\phi} |e_y\rangle) |\uparrow\rangle, \end{aligned}$$
(2)

where $\tan(\theta) = (2\Upsilon_x + \Delta)/\sqrt{\lambda_{SO}^2 + 4\Upsilon_y^2}$, and $\tan(\phi) = 2\Upsilon_y/\lambda_{SO}$. The corresponding eigenenergies read $\omega_{a,b} = -(D \pm \omega_B)/2$ and $\omega_{c,d} = (D \mp \omega_B)/2$, where $D = \sqrt{\lambda_{SO}^2 + 4\Upsilon^2} \approx 2\pi \times 46$ GHz is the intrinsic splitting of the ground states, and $\omega_B = \gamma_s B_z$ is the Zeeman energy. Remarkably, because $\Upsilon_{x,y} \ll \lambda_{SO}$, we can ignore the small distortions of the orbital states induced by the JT effect, then obtain a simplified expression $|a\rangle \approx |e_-,\downarrow\rangle, |b\rangle \approx |e_+,\uparrow\rangle, |c\rangle \approx |e_+,\downarrow\rangle$ and $|d\rangle \approx |e_-,\uparrow\rangle.$

B. Spin-phonon couplings

In this spin-mechanical hybrid device, the timedependent displacement field associated with internal compression modes of the waveguide affect the Coulomb energy of the electronic states, which induces the spinphonon couplings. In the quasi-1D condition, we assume that the orbital degrees of freedom of the SiV centers are coupled to a continuum of compression modes propagating along the x axis [24, 25]. After quantization, the displacement field associated with the propagating phonon modes can be expressed as

$$\vec{u}(\vec{r}) = \sum_{k,n} Q_{n,k}^0 \vec{u}_{n,k}^\perp(y,z) (\hat{b}_{n,k} e^{ikx} + \hat{b}_{n,k}^\dagger e^{-ikx}), \quad (3)$$

where $Q_{n,k}^0$ is the effective zero point fluctuations, $\vec{u}_{n,k}^{\perp}(\vec{r},t)$ is the transverse mode profile, $\hat{b}_{n,k}$ and $\hat{b}_{n,k}^{\dagger}$ are the annihilation and creation operators of the propagating phonons with eigen frequency $\omega_{n,k}$, k is the wave vector, and n is the band index (see Appendix A and B). As a result, the spin-mechanical dynamics for the whole system can be described by Hamiltonian

$$\hat{H}_{sys} = \sum_{j} \hat{H}_{SiV}^{(j)} + \sum_{n,k} \omega_{n,k} \hat{b}_{n,k}^{\dagger} \hat{b}_{n,k} + \sum_{j,n,k} (g_{n,k}^{j} \hat{\sigma}_{-}^{j} \hat{b}_{n,k}^{\dagger} e^{-ikx_{j}} + H.c.), \qquad (4)$$

where j labels the SiV centers located at positions $\vec{r}_j(x_j, y_j, z_j), g_{n,k}^j$ is the spin-phonon coupling constant, and $\hat{\sigma}_{-}^j = (\hat{\sigma}_{+}^j)^{\dagger} = |a^j\rangle\langle c^j| + |b^j\rangle\langle d^j|$ is the spin-conserving lowering operator.

For a waveguide with small size, because the phonon modes are well separated in frequency ($\Delta \omega_n \geq 2\pi \times 50$ MHz), the defect centers are coupled predominantly to only one compression mode of the waveguide (see Appendix C). As a result, the mechanical phonon modes can be simplified to a single standing-wave mode \hat{b} with frequency $\omega_m \sim D \approx 2\pi \times 46$ GHz. In particular, depending on the local strain tensor ε_{ij} and the mode profile $\vec{u}_{n,k}^{\perp}(\vec{r},t)$, the spin-phonon coupling constant for single SiV center can be estimated as [24, 25]

$$g \simeq \frac{d}{v_l} \sqrt{\frac{\hbar\omega_m}{2\rho l w t}},\tag{5}$$

where $d/2\pi \sim 10^{15}$ Hz/strain is the strain sensitivity, v_l is the speed of the longitudinal compression modes in the waveguide, and ρ is the density of diamond.

For the purpose of simplification, we consider the case $B_z \to 0$. Then the SiV center spins can be mapped to a two-level system (i.e., spin- $\frac{1}{2}$ particles) denoted as $|a^j\rangle$ and $|c^j\rangle$, and the spin-conserving lowering operator simplifies to $\hat{\sigma}_{-}^j \to |a^j\rangle \langle c^j|$. We further introduce the collective spin operators $\hat{J}_{-} = (\hat{J}_{+})^{\dagger} = \sum_{j=1}^{N} |a^j\rangle \langle c^j|$, $\hat{J}_x = \frac{1}{2}(\hat{J}_{-} + \hat{J}_{+})$, and $\hat{J}_y = \frac{i}{2}(\hat{J}_{-} - \hat{J}_{+})$, which satisfy the usual angular momentum commutation relations

$$[\hat{J}_{\alpha}, \hat{J}_{\beta}] = i\varepsilon_{\alpha\beta\gamma}\hat{J}_{\gamma}, \quad [\hat{J}_{+}, \hat{J}_{-}] = 2\hat{J}_{z}, \quad [\hat{J}_{z}, \hat{J}_{\pm}] = \pm\hat{J}_{\pm},$$

$$(6)$$

where $\varepsilon_{\alpha\beta\gamma}$ is the Levi-Civita symbol, and $\hat{J}_z = \frac{1}{2} \sum_{j=1}^{N} |c^j\rangle \langle c^j| - |a^j\rangle \langle a^j|$. The Hamiltonian of the whole system then can be represented as

$$\hat{H}_{sys} = \omega_m \hat{b}^{\dagger} \hat{b} + \omega_s \hat{J}_z + g_e (\hat{b}^{\dagger} \hat{J}_- + \hat{b} \hat{J}_+), \qquad (7)$$

where $g_e \simeq \sqrt{Ng}$ is the collective coupling strength, and $\omega_s \sim D \approx 2\pi \times 46$ GHz is the resonance frequency of the SiV spins. Hamiltonian (7) describes a Tavis-Cummings type interaction between an ensemble of SiV spins and a single mechanical phonon mode.

C. Effective model

We now consider the spin-phonon couplings in the large detuning condition $g_e \ll \Delta = |\omega_s - \omega_m|$. In a frame rotating at the mechanical frequency ω_m , the system can be described by Hamiltonian

$$\hat{H}_{I} = \Delta \hat{J}_{z} + g_{e}(\hat{b}^{\dagger}\hat{J}_{-} + \hat{b}^{\dagger}\hat{J}_{+}), \qquad (8)$$

with Δ the detuning of the spin-phonon couplings. To study the phonon-mediated spin-spin coupling interactions, we introduce the Frölich-Nakajima transform

$$\hat{H}_{eff} = e^{-R} \hat{H} e^R, \qquad (9)$$

where $R = g_e(\hat{b}^{\dagger}\hat{J}_--\hat{b}J_+)/\Delta$. By performing the Frölich-Nakajima transform to \hat{H}_I , and using $\hat{J}_+\hat{J}_- = \hat{J}^2 - \hat{J}_z^2 + \hat{J}_z$, to order $(g_e/\Delta)^2$ we obtain an effective Hamiltonian [33, 47]

$$\hat{H}_{eff} \simeq (\Delta + \lambda + 2\lambda \hat{b}^{\dagger} \hat{b}) \hat{J}_z - \lambda \hat{J}_z^2, \qquad (10)$$

where $\lambda = g_e^2/\Delta$ is the coupling strength of the effective spin-spin interactions. In our system, these nonlinear spin-spin couplings are induced by virtual excitations of the mechanical modes. We note that when ignoring the fluctuations of the phonon number $n = \hat{b}^{\dagger}\hat{b}$, the effective Hamiltonian (10) simplifies to a standard one-axis twisting model.

III. EXPERIMENTAL FEASIBILITY

We now consider the experimental feasibility of our scheme and the appropriate parameters to achieve strong couplings. In view of the recent progress in the fabrication of high-quality diamond structures [49–51], and demonstrations of strain-induced control of defects [22– 29], the proposed scheme could realistically be implemented with current experimental techniques. For the diamond waveguides, the material properties are E = 1050Gpa, $\nu = 0.2$, and $\rho = 3500 \text{ kg/m}^3$. The group velocities for a longitudinal compression and a transverse flexural mode are $v_l = 1.7 \times 10^{4}$ m/s and $v_t = 0.73 \times 10^{4}$ m/s, respectively. We consider a quasi-1D diamond waveguide with size $(0.1, 0.1, 20) \ \mu m^3$, then the coupling constant can be estimated as $q \sim 3.4$ MHz for individual SiV centers. For a SiV ensemble with spin number $N \sim 1000$, a collective spin-phonon coupling $g_e \simeq \sqrt{Ng} \sim 100$ MHz can be reached. In the large detuning condition $\Delta \sim 10g_e$, the effective spin-spin coupling strength can

be estimated as $\lambda \simeq g_e^2/\Delta \sim 10$ MHz. By adjusting the size and spin number of the diamond waveguide, these spin-spin couplings could further be enhanced.

In the practical situations, a quality factor $Q \sim 5 \times 10^4$ for the mechanical phonon modes is realistic, which results in a mechanical decay rate $\gamma_m \simeq \omega_m/Q \sim 2\pi \times 1$ MHz. In the low-temperature environment $T \sim 100$ mK, the spin-coherence time of SiV centers can reach ~ 10 ms with dynamical decoupling [15]. Even taking into account the surface effect on SiV centers' decoherence, the spin dephasing rate is still expected to be about $\gamma_s \sim 2\pi \times 100$ kHz. The thermal phonon number $n_{th} \simeq (e^{\hbar \omega_m / k_B T} - 1)^{-1}$ is far below 1 in such low temperature. With these realistic coupling (decay) parameters, we perform numerical simulation for the dynamics of the system, the result is displayed in Fig 3(a). We find that in the practical situations, the effective spin-spin couplings can dominate the decoherence processes, and steer the SiV centers to SSSs as time evolves.

IV. SPIN SQUEEZING

A. The ideal case

We first discuss the spin squeezing of SiV centers in this spin-mechanical hybrid device in the ideal case, then turn to the decoherence effects in the realistic condition. Specifically, the spin squeezing in our system can be introduced by the Heisenberg uncertainty relation. As the collective spin operators $\{\hat{J}_x, \hat{J}_y, \hat{J}_z\}$ obey SU(2) algebra, the associated uncertainty relation $(\Delta \hat{J}_\alpha)^2 (\Delta \hat{J}_\beta)^2 \geq$ $|\langle \hat{J}_\gamma \rangle|^2/4$ can be satisfied. Using optical pumping and microwave spin manipulation, we can firstly preparing the SiV centers to the coherent spin state $|\psi_0\rangle$ along the xaxis, which satisfies $\hat{J}_x |\psi_0\rangle = J |\psi_0\rangle$, where J = N/2. As the coherent spin state is also known as minimumuncertainty state, we have $(\Delta \hat{J}_y)^2 = (\Delta \hat{J}_z)^2 = |\hat{J}_x|/2 =$ J/2, with J/2 the standard quantum limit.

The spin squeezing is defined if the variance of a spin component normal to the mean spin is smaller than the standard quantum limit, i.e., $(\Delta \hat{J}_{\vec{n}_{\perp}})^2 < J/2$. In order to describe the degree of spin squeezing, we introduce the definition of spin squeezing parameter given by Kitagawa and Ueda [32]

$$\xi^{2} = \frac{4(\Delta J_{\vec{n}_{\perp}}^{2})_{\min}}{N}$$
(11)

where $\vec{n}_{\perp} = \sin \alpha \cdot \vec{y} + \cos \alpha \cdot \vec{z}$ refers to an axis perpendicular to the mean-spin direction \vec{x} , and the minimization is over all directions \vec{n}_{\perp} . Note that the spin coherent states and the SSSs can be distinguished by $\xi^2 = 1$ or $\xi^2 < 1$. Further more, as theoretically studied in Ref. [32–34], for spin- $\frac{1}{2}$ particles the minimization spin uncertainty can also be represented as

$$(\Delta \hat{J}_{\vec{n}_{\perp}}^2)_{\min} = \frac{1}{2} (A - \sqrt{B^2 + 4C^2})$$
 (12)

where $A = \langle \hat{J}_y^2 + \hat{J}_z^2 \rangle$, $B = \langle \hat{J}_y^2 - \hat{J}_z^2 \rangle$, and $C = \frac{1}{2} \langle \hat{J}_y \hat{J}_z + \hat{J}_z \hat{J}_y \rangle$.

We now consider preparing the SSSs of SiV centers in our system using the dynamic evolution of the system. Under large detuning condition, we show that the effective spin-spin interactions can be achieved through the spin-phonon couplings. We model these long-range spinspin interactions with the effective Hamiltonian (10), and find that a standard one-axis twisting model can be obtained when ignoring the phonon fluctuations. We remark that the one-axis twisting interaction works in analogy to the squeezing operator, which can steer the system to the SSSs with properly initial states. In particular, this spin squeezing protocol has been implemented in BEC via atomic collisions [52–54] and in atomic ensembles via large detuned atom-field interactions [41]. Moreover, the analytic solutions of the standard one-axis twisting model has been studied in Ref. [32–34]. In our system, as time evolves, the minimization spin uncertainty in the short-time limit ($\lambda t \ll 1$) and large particle number $(J \gg 1)$ can be calculated as

$$(\Delta \hat{J}_{\vec{n}_{\perp}}^2)_{\min} \simeq \frac{J}{2} (\frac{1}{4\alpha^2} + \frac{2}{3}\beta^2).$$
 (13)

where $\alpha = J\lambda t > 1$ and $\beta = J(\lambda t)^2 \ll 1$. In particular, the t_{\min} via minimizing $(\Delta \hat{J}_{\vec{n}_{\perp}}^2)_{\min}$ can be obtained by solving

$$\frac{d(\Delta J_{\vec{n}_{\perp}}^2)_{\min}}{dt}|_{t_{\min}} = 0, \qquad (14)$$

which results in the optimal squeezing time

$$t_{\min} \simeq \frac{3^{1/6}}{\lambda} (2J)^{-2/3}.$$
 (15)

Inserting t_{\min} into Eqs. (11) and (13), we now obtain the optimal squeezing parameter

$$\xi_{opt}^2 \simeq \frac{1}{2} (\frac{2J}{3})^{-2/3}.$$
 (16)

It is observed that the degree of spin squeezing enhanced exponentially by increasing the spin number N.

B. Decoherence effects

Since any quantum system would suffer from decoherence, we now turn to considering the dynamics of the system in the realistic case. As T_1 for SiV centers can reach 1 second in the low-temperature environment, the spin relaxation can be ignored in our discussion. Taking the dephasing (γ_s) of the SiV spins and the decay of the mechanical modes (γ_m) into consideration, the full dynamics of this system can be described by the following master equation:

$$\frac{d\hat{\rho}(t)}{dt} = -i[\hat{H}_{eff}, \hat{\rho}] + \gamma_s \mathcal{D}[\hat{J}_z]\rho + (n_{th} + 1)\Gamma_m \mathcal{D}(\hat{J}_-) + n_{th}\Gamma_m \mathcal{D}(\hat{J}_+), \quad (17)$$

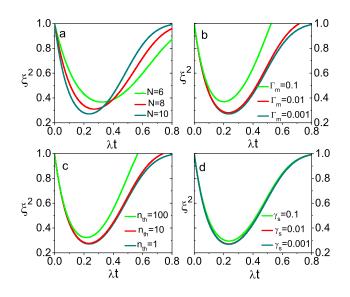


FIG. 2. The effects of spin number and decay parameters to spin squeezing. The dynamic evolution of the system is simulated with different: (a) spin number N, where $\Gamma_m =$ 0.001λ , $n_{th} = 1$, and $\gamma_s = 0.01\lambda$; (b) effective mechanical decay rate Γ_m , where N = 10, $n_{th} = 1$, and $\gamma_s = 0.01\lambda$; (c) thermal phonon number n_{th} , where N = 10, $\Gamma_m = 0.001\lambda$, and $\gamma_s = 0.01\lambda$; (d) spin dephasing rate γ_s , where N = 10, $\Gamma_m = 0.001\lambda$, and $n_{th} = 1$.

where $n_{th} = (e^{\hbar\omega_m/k_BT} - 1)^{-1}$ is the thermal phonon number at the environment temperature T and $\mathcal{D}(\hat{o})\hat{\rho} = \hat{o}\hat{\rho}\hat{o}^{\dagger} - \frac{1}{2}\hat{o}^{\dagger}\hat{o}\hat{\rho} - \frac{1}{2}\hat{\rho}\hat{o}^{\dagger}\hat{o}$ for a given operator \hat{o} . The last two terms describe collective spin relaxation induced by mechanical dissipation, with $\Gamma_m = \gamma_m g_e^2/\Delta^2$.

To study the effects of decoherence processes to spin squeezing, we perform numerical simulations by solving the master Eq. (17) with effective Hamiltonian (10). The simulations are limited in the case for small spin number N, and the initial state is set as the coherent spin state $|\psi_0\rangle$ along the x axis. As illustrated in Fig 2(a), we observe that the spin squeezing can be enhanced by increasing the spin number. In particular, with the increase in N, the time that the system needs to reach the optimal squeezing point will be shortened. In Figs 2(b)and 2(c), we show that the decoherence of the mechanical mode has an obviously harmful effect to the squeezing dynamics. In practical situations, this effect depends on not only the effective mechanical decay rate Γ_m , but also the thermal phonon number n_{th} . The dynamic evolution of the system with different spin dephasing rates is displayed in Fig 2(d). According to the simulation results, the effect of spin dephasing is not so obviously, compared with the mechanical decay.

For spin-mechanical hybrid system with large spin number N, directly solving the master Eq. (17) turn out to be difficult. However, we can still study the dynamics of the system by estimating the mean values of the spin operators. As shown in Eq. (12), in order to estimate the optimal squeezing parameter in our system, a set of spin operators $\{\langle \hat{J}_x \rangle, \langle \hat{J}_y \rangle, \langle \hat{J}_z \rangle, \langle \hat{J}_z^2 \rangle, \langle \hat{J}_z^2 \rangle, \langle \hat{J}_y \rangle \}$ need to be determined, where $\hat{J}_{yz} = \frac{1}{2} \langle \hat{J}_y \hat{J}_z + \hat{J}_z \hat{J}_y \rangle$. Because the initial state satisfying $\hat{J}_x |\psi_0\rangle = J |\psi_0\rangle$, we have $\langle \hat{J}_y \rangle = \langle \hat{J}_z \rangle = \langle \hat{J}_{yz} \rangle = 0$ and $\langle \hat{J}_y^2 \rangle = \langle \hat{J}_z^2 \rangle = J/2$ at the beginning. As theoretically studied in Ref. [47], the mechanical decay (Γ_m) and spin dephasing (γ_s) terms can be treated separately using an approximate numerical approach, and the master Eq. (17) can be linearized in the short time regime. As a result, the evolution of the spin averages can be described by

$$\frac{d\langle \hat{J}_x \rangle}{dt} = -\gamma_s \langle \hat{J}_x \rangle$$

$$\frac{d\langle \hat{J}_y \rangle}{dt} = \lambda J \langle \hat{J}_z \rangle - \gamma_s \langle \hat{J}_y \rangle - \Gamma_m (\tilde{n}_{th} + \frac{1}{2}) \langle \hat{J}_y \rangle + \Gamma_m \langle \hat{J}_{yz} \rangle$$

$$\frac{d\langle \hat{J}_z \rangle}{dt} = -2\Gamma_m (\tilde{n}_{th} + \frac{1}{2}) \langle \hat{J}_z \rangle - \Gamma_m [J(J+1) - \langle \hat{J}_z^2 \rangle]$$

$$\frac{d\langle \hat{J}_y^2 \rangle}{dt} = 2J\lambda \langle \hat{J}_{yz} \rangle - 2\gamma_s (\langle \hat{J}_y^2 \rangle - \frac{J}{2}) + \Gamma_m (J + \frac{1}{2}) \langle \hat{J}_z \rangle$$

$$-2\Gamma_m (\tilde{n}_{th} + \frac{1}{2}) \langle \hat{J}_y^2 - \hat{J}_z^2 \rangle$$

$$\frac{d\langle \hat{J}_z^2 \rangle}{dt} = -2\Gamma_m (\tilde{n}_{th} + \frac{1}{2}) [3\langle \hat{J}_z^2 \rangle - J(J+1)]$$

$$+\Gamma_m \langle \hat{J}_z \rangle [1 - 2J(J + \frac{1}{2})]$$

$$\frac{d\langle \hat{J}_{yz} \rangle}{dt} = \lambda J \langle \hat{J}_z^2 \rangle - \gamma_s \langle \hat{J}_{yz} \rangle - 5(\tilde{n}_{th} + \frac{1}{2}) \Gamma_m \langle \hat{J}_{yz} \rangle$$

$$-\Gamma_m (J^2 - \frac{1}{4}) \langle \hat{J}_y \rangle.$$
(18)

Putting Eqs. (11), (12), and (18) together, we can study the dynamic evolution of our system by numerical simulations. The result is shown in Fig 3(a). As discussed in Sec. III, the relative coupling (decay) parameters are $N \sim 10^3$, $\lambda \sim 10$ MHz, $\Gamma_m \simeq \gamma_m g_e^2/\Delta^2 \sim 10$ kHz, and $\gamma_s \sim 100$ kHz. As the system evolves, we show that

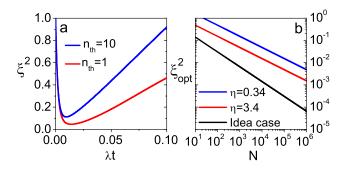


FIG. 3. (a) The spin squeezing dynamics in the practical situation with spin number N = 1000. The related decoherence parameters are $\Gamma_m = 0.001\lambda$, $\gamma_s = 0.01\lambda$, and $n_{th} = \{1, 10\}$. (b) Optimal squeezing parameter ξ_{opt}^2 versus spin number Nin the ideal and realistic cases. In the practical case, the single-spin coupling-to-decay ratios are $\eta = \{3.4, 0.34\}$ for $n_{th} = \{1, 10\}$, respectively.

the optimal squeezing parameters $\{0.046, 0.112\}$ can be reached for $n_{th} = \{1, 10\}$, respectively.

As illustrated in Ref. [47] for NV centers, the linearization of the master equation may also result in some formulas to estimate the optimal squeezing parameter for a system with arbitrary large spin number N. By introducing the single-spin coupling-to-decay ratio $\eta = g/\max\{n_{th}\gamma_m, \gamma_s\}$, the optimal squeezing parameter can be estimated as

$$\xi_{opt}^2 \simeq \frac{2}{\sqrt{J\eta}},\tag{19}$$

with optimal squeezing time $t_{\min} \simeq 1/(\gamma_s \sqrt{J\eta})$. In comparison, the estimated optimal spin squeezing parameters in the ideal case and in the realistic case are shown in Fig 3 (b). These results are obtained by solving the Eqs. (16) and (19), respectively. We observe that for both the two cases, the spin squeezing degree can be enhanced exponentially by increasing the spin number.

V. DISCUSSION AND CONCLUSION

We now take a further consideration about the phonon number fluctuations in our system. In particular, we mention that the phonon fluctuation term $\propto \hat{b}^{\dagger}\hat{b}\hat{J}_z$ in effective Hamiltonian (10) could also be utilized for spin squeezing through a cavity feedback scheme. Remarkably, this cavity feedback spin squeezing protocol has already been experimentally studied with ultracold atoms [55–57]. In our setup, it can be performed by driving the mechanical phonon modes [47]. On the other hand, the phonon number $n = \hat{b}^{\dagger}\hat{b}$ couples to \hat{J}_z , which may also result in additional spin dephasing due to thermal number fluctuations. Together with the inhomogeneous broadening of the spin ensemble, it may limit the long spin-coherence time of SiV centers. However, we remind that these effects can be effectively suppressed by the spin-echo techniques [58, 59].

In summary, we present an efficient scheme for squeezing the SiV center spins in an exquisite spin-mechanical hybrid device. We show that, the strain couplings between the SiV spins and the compression phonon modes allow long-range spin-spin interactions in the large detuning condition. By modeling these nonlinear spin-spin couplings with an effective one-axis twisting Hamiltonian, we find that the SiV centers with properly initial states can be steered to the SSSs as the system evolves. Further more, we study the effects of decoherence processes with numerical simulations, showing that in the practical conditions, the SiV spin ensemble with a spin number $N \sim 10^3$, can be strongly squeezed in the low-temperature environment $T\,\sim\,100\,$ mK . This spin-mechanical hybrid architecture provides a promising platform for studying the SSSs with spin-phonon couplings, which may further be applied in entanglement detection, quantum information, and high-precision measurement.

ACKNOWLEDGMENTS

Bo Li thanks Yuan Zhou for fruitful discussions. Pengbo Li was supported by the NSFC under Grant Nos. 11774285, 91536115 and 11534008, and the Fundamental Research Funds for the Central Universities. Tongcang Li acknowledges supports from the Gordon and Betty Moore Foundation, the Purdue EFC research grant, and the NSF under grant No. PHY-1555035. Part of the simulations are coded in PYTHON using the QUTIP library [60].

Appendix A: Calculation of mechanical compression modes in diamond waveguide

In the main text we show that our setup is realized by a diamond waveguide with size (l, w, t), and we focus on the case $l \gg \{w, t\}$. We now discuss the mechanical compression modes propagating along the waveguide. With the framework of elastic mechanical theory, the mechanical modes can be treated as a continuous displacement field $\vec{u}(\vec{r}, t)$. For a linear, isotropic medium, the motional equation of the time-dependent displacement field reads

$$\rho \frac{\partial^2}{\partial t^2} \vec{u}(\vec{r},t) = (\lambda + \mu) \vec{\nabla} (\vec{\nabla} \cdot \vec{u}(\vec{r},t)) + \mu \vec{\nabla}^2 \vec{u}(\vec{r},t), \quad (A1)$$

where ρ is the mass density of the diamond. Specifically, the Lamé constants λ and μ can be expressed in terms of the Young's modulus E and the Poisson ratio ν , i.e.,

$$\lambda = \frac{\nu E}{(1+\nu)(1-2\nu)}, \mu = \frac{E}{2(1+\nu)}.$$
 (A2)

For a diamond waveguide, we have $\rho = 3500 \text{ kg/m}^3$, E = 1050 Gpa and $\nu = 0.2$. By assuming periodic boundary conditions, the motional equation (A1) can be solved by the general ansatz

$$\vec{u}(\vec{r},t) = \frac{1}{\sqrt{2}} \sum_{k,n} \vec{u}_{n,k}^{\perp}(y,z) [A_{n,k}(t)e^{ikx} + A_{n,k}^*e^{-ikx}],$$
(A3)

where the index n denotes the different phonon branches, and $k = 2\pi/L \times m$ labels the wavevector along the x-axis. Note that the amplitudes $A_{n,k}(t)$ and the mode frequencies $\omega_{n,k}$ satisfy $\ddot{A}_{n,k}(t) + \omega_{n,k}^2 A_{n,k}(t) = 0$. Together with the transverse mode profile $\vec{u}_{n,k}^{\perp}(x, y)$, they can be calculated by the finite-element-method simulations for a waveguide with arbitrary size.

Appendix B: Quantization of the displacement field

We now consider the propagating phonon modes supported by the diamond waveguide in the quantum regime. Using a quantization method similar to that used for the electromagnetic field in quantum optics, the motion of the diamond lattices associated with the propagating phonons can be quantized. As a result, the quantized displacement field can be represented as

$$\vec{u}(\vec{r}) = \sum_{k,n} Q_{n,k}^0 \vec{u}_{n,k}^\perp(y,z) (\hat{b}_{n,k} e^{ikx} + \hat{b}_{n,k}^\dagger e^{-ikx}), \quad (B1)$$

where $\hat{b}_{n,k}$ and $\hat{b}_{n,k}^{\dagger}$ are the annihilation and creation operators of the phonons, which can be defined as

$$\hat{b}_{n,-k} = \frac{1}{2} \left(\frac{\hat{Q}_{n,k}}{Q_{n,k}^0} + \frac{i\hat{P}_{n,k}}{P_{n,k}^0} \right), \\ \hat{b}_{n,k}^\dagger = \frac{1}{2} \left(\frac{\hat{Q}_{n,k}}{Q_{n,k}^0} - \frac{i\hat{P}_{n,k}}{P_{n,k}^0} \right).$$
(B2)

Here $\hat{Q}_{n,k}$ and $\hat{P}_{n,k}$ denote the generalized coordinate and momentum operators, which satisfying the canonical commutation relations $[\hat{Q}_{n,k}, \hat{P}_{n,k}] = i\hbar\delta_{n,n'}\delta_{kk'}$. In particular, the effective zero point fluctuations of the phonon modes can be estimated as $Q_{n,k}^0 = \sqrt{\hbar/(2\rho V_{eff}\omega_{n,k})}$ and $P_{n,k}^0 = \sqrt{(\hbar\rho V_{eff}\omega_{n,k})/2}$. Further more, the resulting Hamiltonian for the propagating phonons reads

$$\hat{H}_{ph} = \sum_{k,n} \hbar \omega_{n,k} \hat{b}^{\dagger}_{n,k} \hat{b}_{n,k}.$$
 (B3)

Appendix C: Description of the spin-phonon couplings

In our system, the time-dependent displacements of the lattice atoms forming the defect centers affect the defects' electronic structure, which results in the strain couplings between the propagating phonons and the orbital degrees of freedom of the SiV centers. As described in the main text, we assume the symmetry axis of the SiV centers is along the z axis, and the propagating phonon modes supported by the waveguide is along the x axis. Then the strain tensor can be defined as

$$\epsilon_{ij} = \frac{1}{2} \left(\frac{\partial u_i}{\partial x_j} + \frac{\partial u_j}{\partial x_i} \right), \tag{C1}$$

with $u_{i(j)}$ denoting the quantized displacement field with subscripts $i, j \in \{x, y, z\}$. For a small stress, the effect of lattice deformation is linear in the strain components and is captured by Hamiltonian

$$\hat{H}_{strain} = \sum_{i,j} V_{ij} \epsilon_{ij}, \qquad (C2)$$

where V_{ij} are the particular strain components acting on the SiV electronic levels.

The Hamiltonian H_{strain} can be rewritten with Group theory in terms of basis-independent linear combinations of strain components adapted to the symmetries of the SiV center. These combinations can be viewed as particular modes of deformation, and the resulting effects on the orbital wave functions can be deduced using group theory. Specifically, by projecting the strain tensor onto the irreducible representations of the point group of the SiV center (D_{3d}) , we arrive at

$$\hat{H}_{strain} = \sum_{l} V_l \epsilon_l, \tag{C3}$$

where each ϵ_l denotes a linear combination of strain components ϵ_{ij} , and corresponds to specific symmetries indicated by the subscript l, i.e.,

$$\epsilon_{A_{1g}} = t_{\perp}(\epsilon_{xx} + \epsilon_{yy}) + t_{\parallel}\epsilon_{zz},$$

$$\epsilon_{E_{gx}} = d(\epsilon_{xx} - \epsilon_{yy}) + f\epsilon_{zx},$$

$$\epsilon_{E_{gy}} = -2d\epsilon_{xy} + f\epsilon_{yz}.$$
(C4)

Here, $t_{\perp}, t_{\parallel}, d$ and f are four strain-susceptibility parameters, which are related to the original stress-response coefficients. The effects of these strain components on the electronic states can be represented as

$$\begin{split} V_{A_{1g}} &= |e_x\rangle \langle e_x| + |e_y\rangle \langle e_y|, \\ V_{E_{gx}} &= |e_x\rangle \langle e_x| - |e_y\rangle \langle e_y|, \\ V_{E_{gy}} &= |e_x\rangle \langle e_y| + |e_y\rangle \langle e_x|. \end{split} \tag{C5}$$

As coupling to symmetric local distortions (~ $\epsilon_{A_{1g}}$) shifts all ground states equally, it can be ignored in our discussion. In the basis spanned by the eigenstates of the spin-orbit coupling $\{|e_{-}\rangle, |e_{+}\rangle\}$, the strain Hamiltonian can be rewritten as

$$\hat{H}_{strain} = \epsilon_{E_{gx}} (\hat{L}_{-} + \hat{L}_{+}) - i\epsilon_{E_{gy}} (\hat{L}_{-} - \hat{L}_{+}), \quad (C6)$$

where $\hat{L}_{+} = (\hat{L}_{-})^{\dagger} = |c\rangle\langle a| + |d\rangle\langle b|$ is the orbital raising operator within the ground states. By decomposing the local displacement field as in Eq. (B1), the spin-phonon couplings under the rotating-wave approximation can be expressed as

$$\hat{H}_{strain} \simeq \sum_{j,n,k} [(g_{n,k}^j \hat{\sigma}_{+\uparrow}^j + g_{n,-k}^{j*} \hat{\sigma}_{+\downarrow}^j) \hat{b}_{n,k} e^{ikx_j} + H.c.],$$
(C7)

where $\hat{\sigma}^{j}_{+\uparrow} = |c^{j}\rangle\langle a^{j}|$ and $\hat{\sigma}^{j}_{+\downarrow} = |d^{j}\rangle\langle b^{j}|$. Here the spinphonon coupling strength is given by

$$g_{n,k} = \frac{d}{v_l} \sqrt{\frac{\hbar\omega_{n,k}}{2\rho l w t}} \zeta_{n,k}(\vec{r}), \qquad (C8)$$

and the dimensionless profile reads

$$\zeta_{n,k}(\vec{r}) = \frac{1}{|k|} [(iku_{n,k}^{\perp,x} + ik\frac{f}{2d}u_{n,k}^{\perp,z} + \frac{f}{2d}\partial_z u_{n,k}^{\perp,x} - \partial_y u_{n,k}^{\perp,y}) -i(iku_{n,k}^{\perp,y} + \partial_y u_{n,k}^{\perp,x} + \frac{f}{2d}\partial_y u_{n,k}^{\perp,z} + \frac{\partial_z u_{n,k}^{\perp,y}}{2})].$$
(C9)

For the compression phonon modes propagating along the *x*-axis, the mode function can be approximated as $\vec{u}_{n,k}(\vec{r}) \sim \vec{e}_x \cos(\omega_{n,k}x/v_l)$, resulting in $|\zeta_{n,k}(\vec{r})| \sim 1$.

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